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Benefits. High frequency DC-DC converters. Switched mode power supplies DC to DC converters IRFRN, IRFUN Datasheet by Infineon Technologies. IRFRN. Low Gate to Drain Charge to FRN Datasheet. N-channel enhancement mode field-effect transistor in a plastic package using TrenchMOS™ 1 technology. Switching Losses Part: IIRFRN. HEXFET® Power MOSFET. N-channel enhancement mode field-effect transistor in a plastic package using TrenchMOS™ 1 technology. International IGER Rectifier f. Benefits. Data and specifications subject to change without notice/ Note: For the most current drawings please refer to the IR site at IRFRN. The IR MOSFET family of power MOSFETs utilizes proven silicon processes offering designers a wide portfolio of devices to support various applications such as DC motors, inverters, SMPS, lighting, load switches as well as battery powered devices Description. Description: N-Channel MOSFET Transistor Description. V Single N-Channel IR MOSFET in a D-Pak package. Overview. Applications. PDIRFRN IRFUN. Product availability: IRFR in SOT (D-PAK)When mounted on 1 square PCB (FRor G Material). I High frequency DC-DC converters. Product availability: IRFR in SOT (D-PAK)Features. Applications. * For recommended footprint and soldering techniques refer to application noteAN IR WORLD IRFRN. When mounted on 1 square PCB (FRor G Material). IRFRN. Overview. Datasheet: Kb/2P. IRFUN. Manufacturer: Inchange Semiconductor Company Limited. Download PDF Datasheet Feedback/Errors. I Low Gate to Drain Charge to Reduce. V Single N-Channel IR MOSFET in a D-Pak g: pdf SMPS MOSFET. * For recommended footprint and soldering techniques refer to application noteAN IR WORLD HEADQUARTERSKansas St., El Segundo, California, USA Tel: () TAC Fax: () Visit us at for sales contact information IR WORLD HEADQUARTERSKansas St., El Segundo, California, USA Tel: () TAC Fax: () Visit us at for sales contact information. Fast switching Low on-state resistance Surface mount packageApplications. SMPS MOSFET HEXFET® Power MOSFET.

 Difficulté **Difficile**

 Durée **452 jour(s)**

 Catégories **Art, Énergie, Alimentation & Agriculture, Sport & Extérieur, Science & Biologie**

 Coût **800 EUR (€)**

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Matériaux

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